

Technical Data Data Sheet N1925, Rev. - Green Products

RDBF31(H) THRU RDBF310(H)

SINGLE PHASE 3.0 AMP FAST GLASS PASSIVATED BRIDGE RECTIFIER

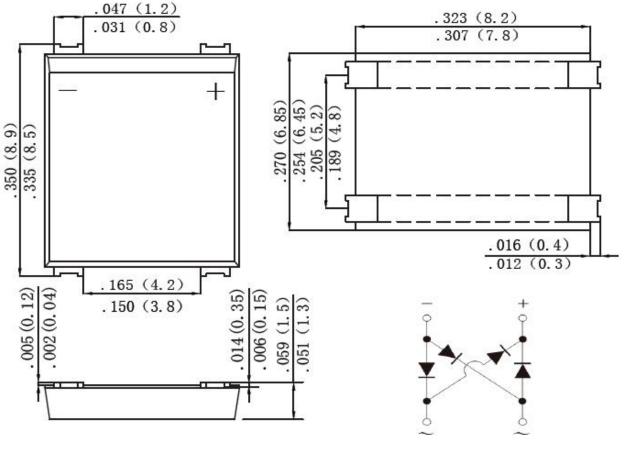
Features:

- Glass passivated die construction
- Low leakage
- Ideal for printed circuit board
- Surge overload rating-100A peak
- Designed for surface mount application
- Plastic material-UL flammability 94V-0

Mechanical Data:

- Case: DBF, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Marking: Type Number

Mechanical Dimensions: In Inches/mm



DBF

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Maximum Ratings and Electrical Characteristics Rating at 25°C ambient temperature unless otherwise specified. Single Phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Maximum Ratings:

Type Number	Symbol	RDBF31 (H)	RDBF32 (H)	RDBF34 (H)	RDBF36 (H)	RDBF38 (H)	RDBF310 (H)	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	100	200	400	600	800	1000	v
RMS Reverse Voltage	V _{RMS}	70	140	280	420	560	700	V
Average Rectified Output Current (Note 2) $@T_A = 120^{\circ}C$	lo	3.0						А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100						А

Electrical Characteristics:

Type Number	Symbol	RDBF31 (H)	RDBF32 (H)	RDBF34 (H)	RDBF36 (H)	RDBF38 (H)	RDBF310 (H)	Unit
Forward Voltage (per element) @I _F =3.0A	VF	1.3						V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I _R	5.0 500						μA
Typical Junction Capacitance(per leg) (Note 4)	CJ	45						pF
I ² t Rating for fusing (t <8.3ms)	l²t	41.5						A ² s
Maximum reverse recovery time (Note 3)	T _{RR}	150 250 500				00	ns	

Thermal-Mechanical Specifications:

Type Number	Symbol	RDBF31 (H)	RDBF32 (H)	RDBF34 (H)	RDBF36 (H)	RDBF38 (H)	RDBF310 (H)	Unit
Typical Thermal Resistance (per leg)(Note 5)	R _{θJA} R _{θJC}	15 5						°C/W
Operating and Storage Temperature Range	Tj, Tstg	-55 to +150						°C

Note:1. "H": Halogen Free.

2. Mounted on glass epoxy PC board with 1.3mm² solder pad.

3. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A.

4. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

5. Mounted on 15 mm*12 mm*1.6 mm AL pad attach 195 mm*110 mm*10 mm steel plate

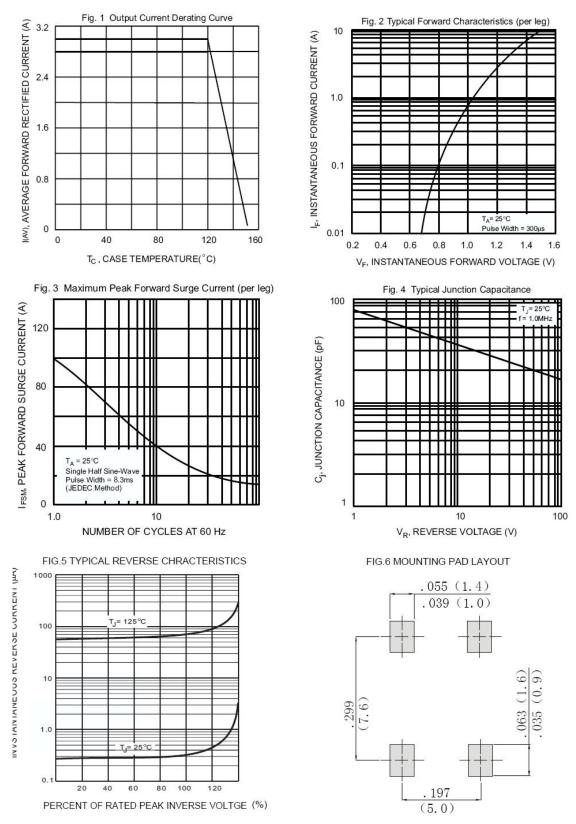
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